

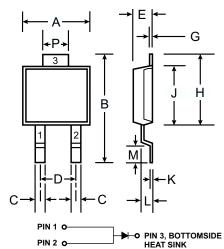
10A LOW VF SCHOTTKY BARRIER RECTIFIER POWERMITE® 3

Features

- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- High Surge Capability
- High Max Junction Temperature Rating
- Very Low Forward Voltage Drop
- Very Low Leakage Current
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications
- Plastic Material: UL Flammability Classification Rating 94V-0

Mechanical Data

- Case: POWERMITE®3, Molded Plastic
- Terminals: Solderable per MIL-STD-202, Method 208
- Polarity: See Diagram
- Weight: 0.072 grams (approx.)
- Marking information: See sheet 3



POWERMITE®3			
Dim	Min	Max	
Α	4.03	4.09	
В	6.40	6.61	
С	.889 NOM		
D	1.83 NOM		
E	1.10	1.14	
G	.178 NOM		
Н	5.01	5.17	
J	4.37	4.43	
K	.178 NOM		
L	.71	.77	
М	.36	.46	
Р	1.73	1.83	
All Dimensions in mm			

Note: Pins 1 & 2 must be electrically connected at the printed circuit board.

Maximum Ratings @ T_A = 25°C unless otherwise specified

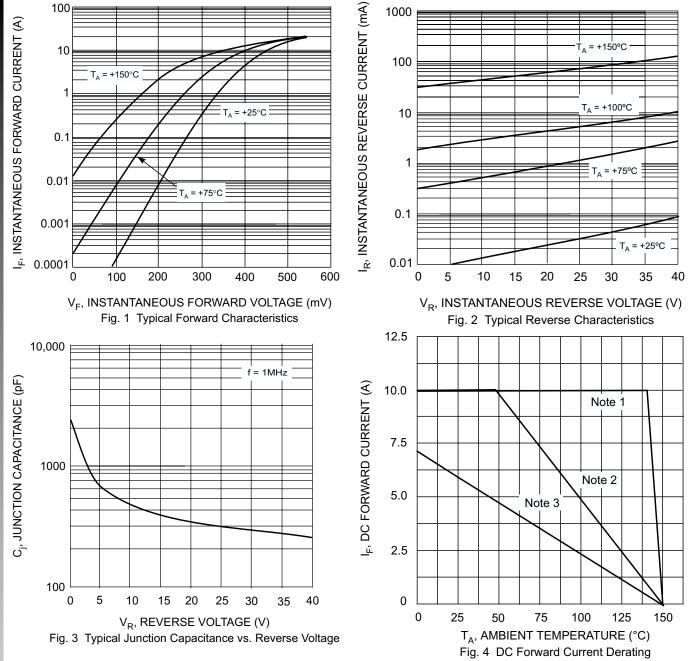
Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	40	٧
RMS Reverse Voltage	V _{R(RMS)}	28	V
Average Rectified Output Current (see also Figure 4)	Io	10	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave Superimposed on Rated Load (JEDEC Method) @TC = 88°C	I _{FSM}	150	А
Typical Thermal Resistance Junction to Soldering Point	R _{0JS}	2.5	°C/W
Operating Temperature Range	Tj	-65 to +150	°C
Storage Temperature Range	T _{STG}	-65 to +150	°C

Electrical Characteristics @ T_A = 25°C unless otherwise specified

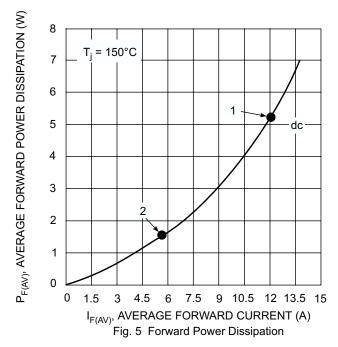
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 1)	V _{(BR)R}	40	_	_	V	I _R = 1mA
Forward Voltage (Note 1)	V _{FM}		0.45 — 0.47	0.49 0.41 0.51	V	$\begin{array}{l} I_F = 8A, \ T_S = \ 25^{\circ}C \\ I_F = 8A, \ T_S = 125^{\circ}C \\ I_F = 10A, \ T_S = \ 25^{\circ}C \end{array}$
Peak Reverse Current (Note 1)	I _{RM}		0.1 12.5	0.3 25	mA	T _S = 25°C, V _R = 35V T _S = 100°C, V _R = 35V
Junction Capacitance	Cj	_	700	_	pF	f = 1.0MHz, V _R = 4.0V DC

Notes: 1. Short duration test pulse used to minimize self-heating effect.



Notes:

- 1. $T_A = T_{SOLDERING\ POINT}$, $R_{\theta JS} = 2.5^{\circ}C/W$, $R_{\theta SA} = 0^{\circ}C/W$.
 - 2. Device mounted on GETEK substrate, 2"x2", 2 oz. copper, double-sided, cathode pad dimensions 0.75" x 1.0", anode pad dimensions 0.25" x 1.0". $R_{\theta JA}$ in range of 15-30°C/W.
 - Device mounted on FR-4 substrate, 2"x2", 2 oz. copper, single-sided, pad layout as per Diodes Inc. suggested pad layout document AP02001 which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf. R_{θJA} in range of 60-75°C/W.



Notes:

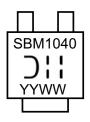
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Ordering Information (Note 3)

Device	Packaging	Shipping
SBM1040-13	POWERMITE®3	5000/Tape & Reel

Notes: 3. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



SBM1040 = Product type marking code

O!! = Manufacturers' code marking

YYWW = Date code marking

YY = Last two digits of year ex: 02 for 2002

WW = Week code 01 to 52